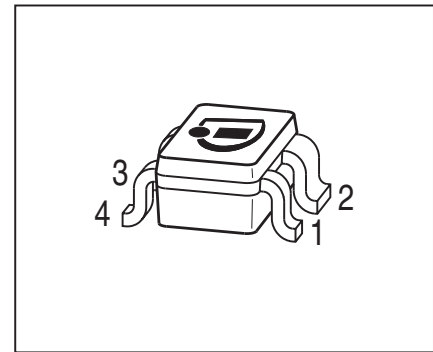
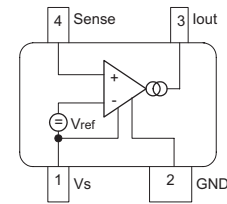


**Active Bias Controller**
**Characteristics**

- Supplies stable bias current from 1.8V operating voltage on
- Low voltage drop:  
110mV for 10mA collector current


**Application notes**

- Stabilizing bias current of NPN transistors and FET's from 100µA to 20mA
- Ideal supplement for Sieget and other transistors



- Pb-free (RoHS compliant) package<sup>1)</sup>
- Qualified according AEC Q101



Type	Marking	Pin Configuration				Package
BCR410W	W8s	1= Vs	2=GND	3=Iout	4=Sense	SOT343

**Maximum Ratings**

Parameter	Symbol	Value	Unit
Supply voltage	$V_S$	18	V
Output current	$I_{out}$	0.5	mA
Total power dissipation, $T_S = 110\text{ °C}$	$P_{tot}$	100	mW
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-65 ... 150	

**Thermal Resistance**

Junction - soldering point <sup>2)</sup>	$R_{thJS}$	≤ 470	K/W
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<sup>1)</sup>Pb-containing package may be available upon special request

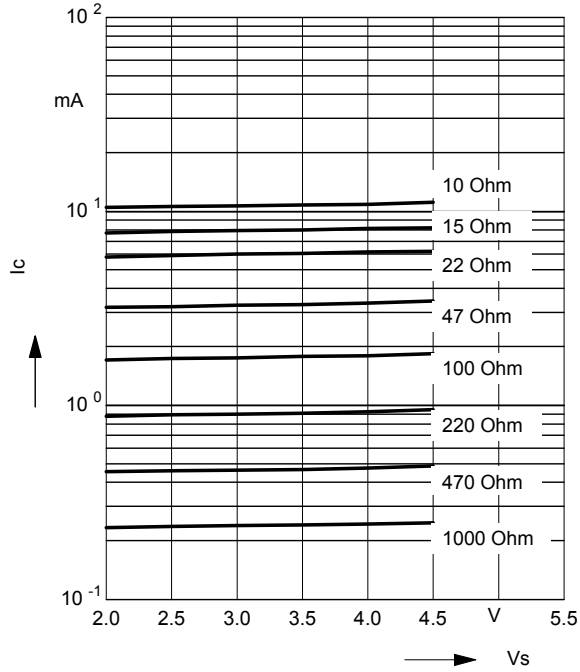
<sup>2)</sup>For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

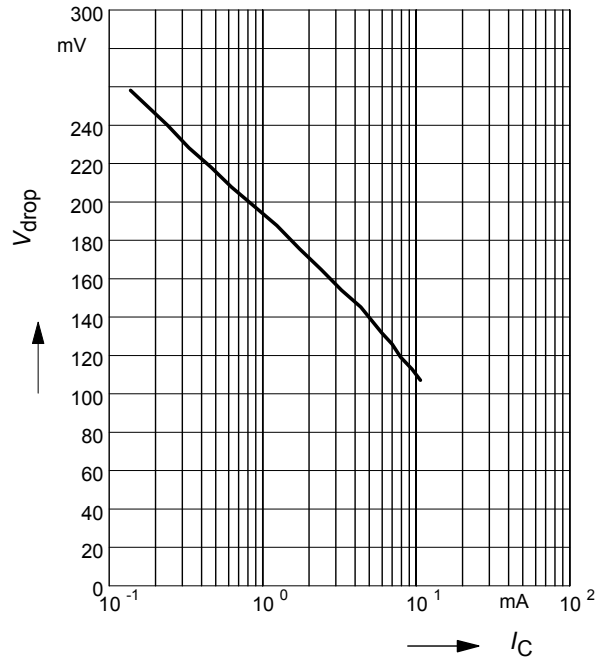
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC Characteristics</b>					
Additional current consumption $V_S = 3\text{ V}$	$I_0$	-	200	400	$\mu\text{A}$
<b>DC Characteristics with stabilized NPN-Transistors</b>					
Lowest sufficient battery voltage	$V_{S\text{min}}$	-	1.8	-	V
Voltage drop $I_C = 10\text{ mA}$	$V_{\text{drop}}$	-	110	-	mV
Change of $I_C$ versus $h_{FE}$ $h_{FE} = 50$	$\Delta I_C / I_C$	-	tbd	-	$\Delta h_{FE} / h_{FE}$
Change of $I_C$ versus $V_S$ $V_S = 3\text{ V}$	$\Delta I_C / I_C$	-	2	-	%/V
Change of $I_C$ versus $T_A$	$\Delta I_C / I_C$	-	0.15	-	%/K

**Collector Current  $I_C = f(V_S)$**   
of stabilized NPN Transistor

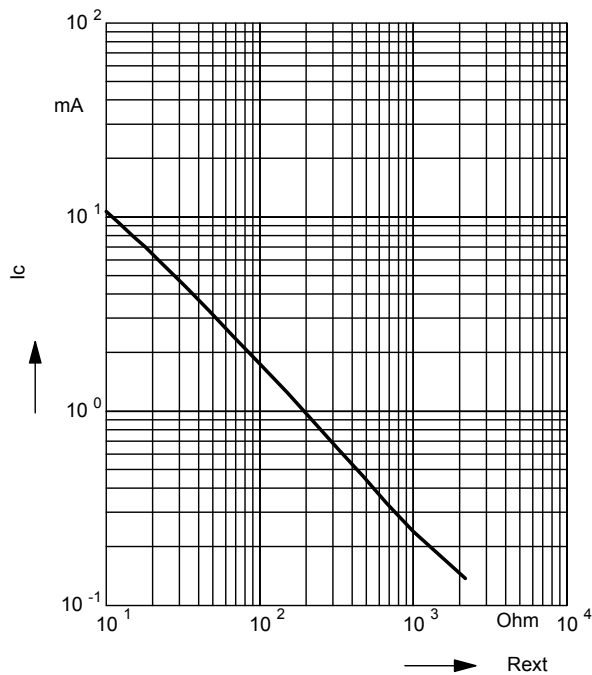
Parameter  $R_{ext.}$  ( $\Omega$ )



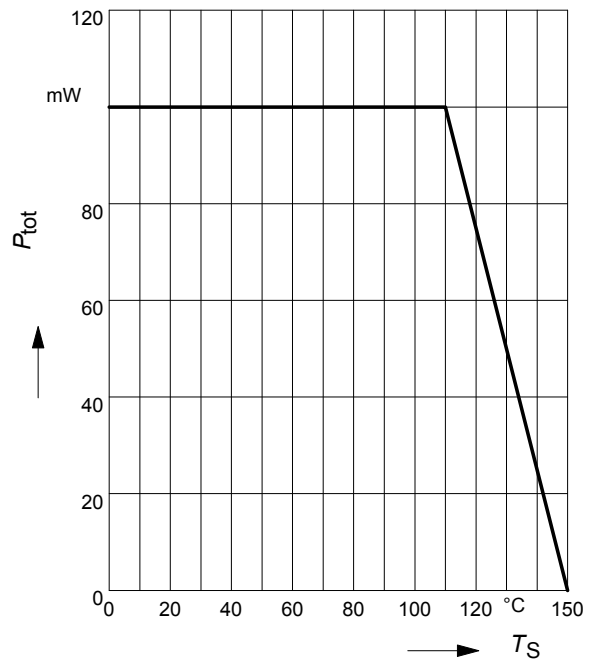
**Voltage drop  $V_{drop} = f(I_C)$**



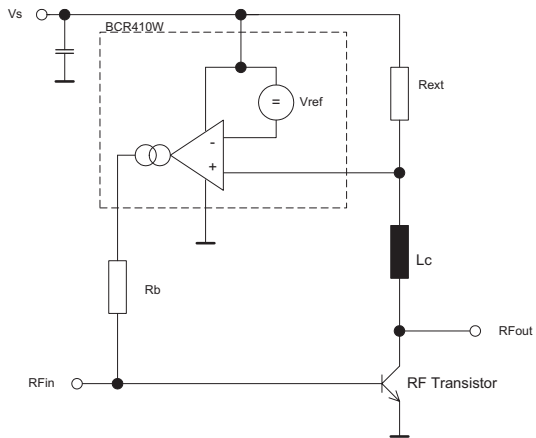
**Collector current  $I_C = f(R_{ext.})$**   
of stabilized NPN Transistor



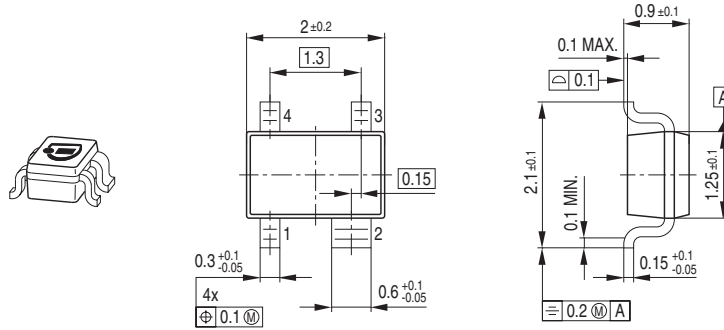
**Total power dissipation  $P_{tot} = f(T_S)$**



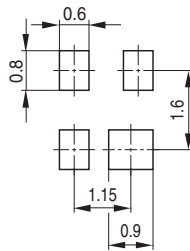
**Application Circuit:**



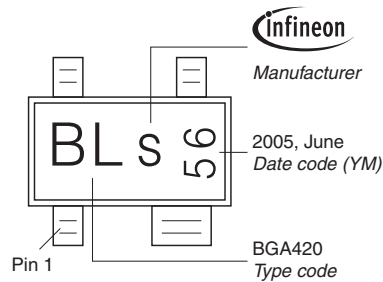
Package Outline



Foot Print

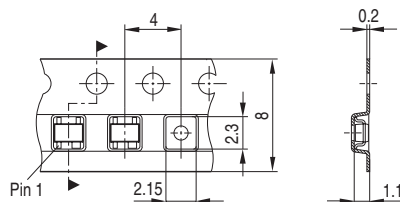


Marking Layout (Example)



Standard Packing

Reel  $\varnothing$ 180 mm = 3.000 Pieces/Reel  
 Reel  $\varnothing$ 330 mm = 10.000 Pieces/Reel



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